#### NCE N-Channel Enhancement Mode Power MOSFET

#### **Description**

The NCE1490 uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

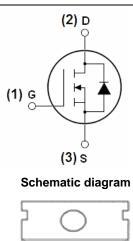
- $V_{DS} = 140V, I_D = 90A$  $R_{DS(ON)} < 13m\Omega @ V_{GS} = 10V (Typ:10.5m\Omega)$
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

#### **Application**

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% ΔVds TESTED!





Marking and pin assignment



**Package Marking and Ordering Information** 

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE1490	NCE1490	TO-220-3L	-	-	-

Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	140	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	I <sub>D</sub>	90	Α
Drain Current-Continuous(T <sub>C</sub> =100°C)	I <sub>D</sub> (100℃)	63	Α
Pulsed Drain Current	I <sub>DM</sub>	260	Α
Maximum Power Dissipation	P <sub>D</sub>	310	W
Derating factor		2.07	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	1701	mJ



# http://www.ncepower.com

# NCE1490

Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 175	$^{\circ}$ C			
Thermal Characteristic						
Thermal Resistance, Junction-to-Case (Note 2)	Rejc	0.48	°C/W			

# Electrical Characteristics (T<sub>C</sub>=25 °C unless otherwise noted)

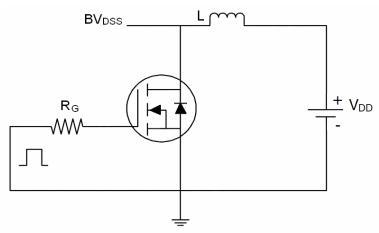
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	140	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =140V,V <sub>GS</sub> =0V	-	-	1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250μA	2	3	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =30A	-	10.5	13	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =15V,I <sub>D</sub> =40A	120	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	\/ <b>5</b> 0\/\/ 0\/	-	8000	-	PF
Output Capacitance	Coss	V <sub>DS</sub> =50V,V <sub>GS</sub> =0V,	-	463	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	352	-	PF
Switching Characteristics (Note 4)	•					
Turn-on Delay Time	t <sub>d(on)</sub>		-	40	-	nS
Turn-on Rise Time	t <sub>r</sub>	VDD=50V,ID=2A,RL=15Ω,	-	38	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	RG=2.5Ω,VGS=10V	-	140	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	60	-	nS
Total Gate Charge	Qg		-	160	-	nC
Gate-Source Charge	Q <sub>gs</sub>	ID=30A,VDD=50V,VGS=10V	-	31	-	nC
Gate-Drain Charge	$Q_{gd}$		-	64	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =40A	-	0.82	1.2	V
Diode Forward Current (Note 2)	Is		-	-	90	Α
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF = 40A	-	42	1	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	69	1	nC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				y LS+LD)

#### Notes:

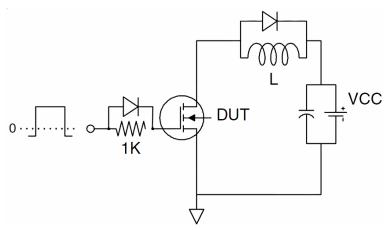
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- $\textbf{4.} \ \textbf{Guaranteed by design}, \ \textbf{not subject to production}$
- 5. E\_{AS} condition : Tj=25  $^{\circ}\text{C}$  ,V\_DD=50V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$

### **Test Circuit**

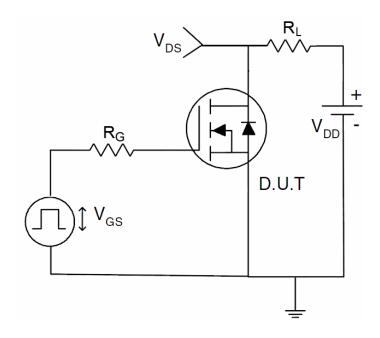
# 1) E<sub>AS</sub> test Circuit



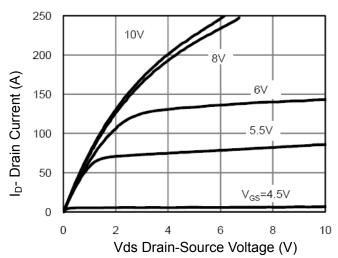
#### 2) Gate charge test Circuit



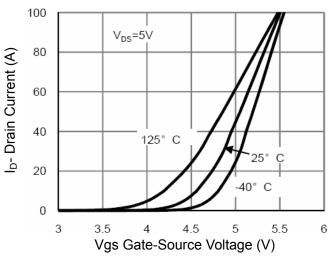
# 3) Switch Time Test Circuit



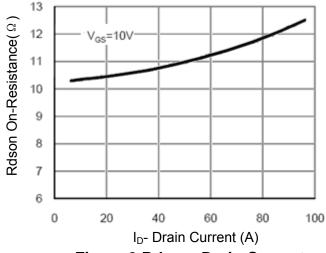
## **Typical Electrical and Thermal Characteristics (Curves)**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 



**Figure 3 Rdson- Drain Current** 

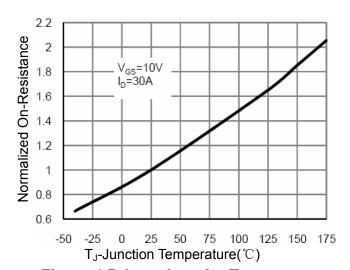


Figure 4 Rdson-JunctionTemperature

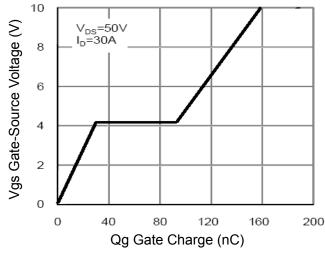


Figure 5 Gate Charge

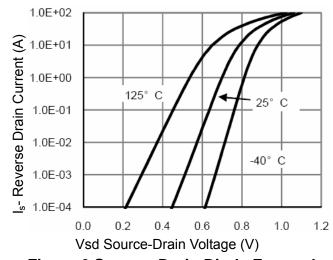


Figure 6 Source- Drain Diode Forward

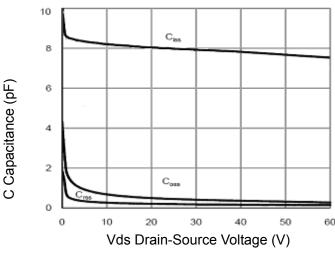


Figure 7 Capacitance vs Vds

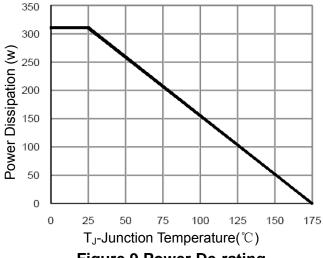
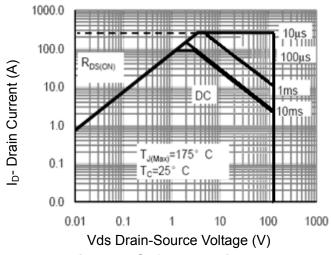


Figure 9 Power De-rating



**Figure 8 Safe Operation Area** 

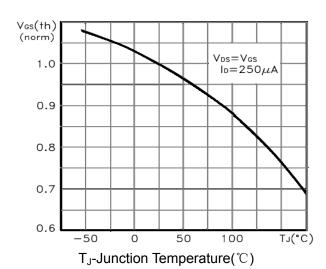


Figure 10 V<sub>GS(th)</sub> vs Junction Temperature

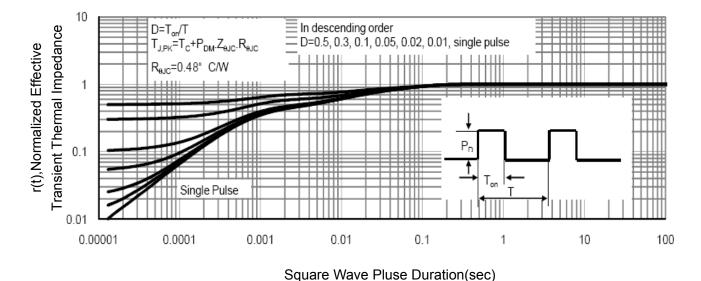
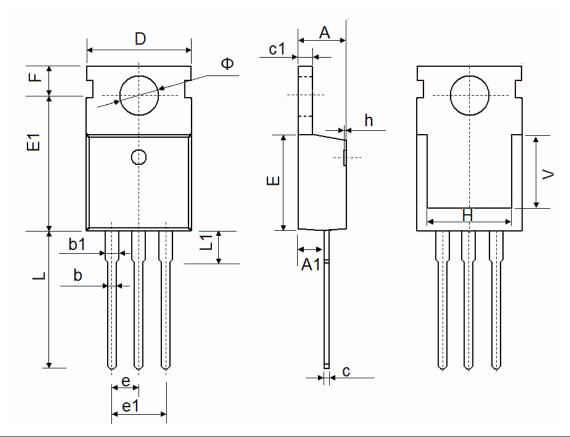


Figure 11 Normalized Maximum Transient Thermal Impedance

# **TO-220-3L Package Information**



Cumbal	Dimensions	In Millimeters	Dimensions In Inches				
Symbol	Min.	Max.	Min.	Max.			
А	4.400	4.600	0.173	0.181			
A1	2.250	2.550	0.089	0.100			
b	0.710	0.910	0.028	0.036			
b1	1.170	1.370	0.046	0.054			
С	0.330	0.650	0.013	0.026			
c1	1.200	1.400	0.047	0.055			
D	9.910	10.250	0.390	0.404			
Е	8.9500	9.750	0.352	0.384			
E1	12.650	12.950	0.498	0.510			
е	2.540	2.540 TYP.		0.100 TYP.			
e1	4.980	5.180	0.196	0.204			
F	2.650	2.950	0.104	0.116			
Н	7.900	8.100	0.311	0.319			
h	0.000	0.300	0.000	0.012			
L	12.900	13.400	0.508	0.528			
L1	2.850	3.250	0.112	0.128			
V	7.500	7.500 REF.		0.295 REF.			
Ф	3.400	3.800	0.134	0.150			

Pb Free Product

NCE1490

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